Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S10	15	US-2911706-\$.DID. OR US-2980830-\$.DID. OR US-3136197-\$.DID. OR US-3345422-\$.DID. OR US-3430109-\$.DID. OR US-3500139-\$.DID. OR US-3515956-\$.DID. OR US-3520139-\$.DID. OR US-3581161-\$.DID. OR US-3586432-\$.DID. OR US-3622382-\$.DID. OR US-4139442-\$.DID. OR US-4916413-\$.DID. OR US-5040034-\$.DID. OR	USPAT	ADJ	ON	2005/12/07 13:25
S11	8	("3534234" "3586542" "3622382" "3648125" "3649386").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2005/11/08 10:41
S12	4	(("5254218") or ("5361326")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/08 10:42
S14	1	us-20040144999-\$.did.	US-PGPUB; USPAT	ADJ	ON	2005/12/08 07:38
S15	1	S14 and ("25" "24R" 25e "27")	US-PGPUB; USPAT	OR	ON	2005/12/07 13:57
S16	1	S14 and magnification	US-PGPUB; USPAT	OR	ON	2005/12/07 14:00
S17	1	S14 and depth	US-PGPUB; USPAT	OR	ON	2005/12/07 14:13
S18	5	(("5361326") or ("5082793") or ("4946800") or ("3585714") or ("3430109")).PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/07 14:14
S19	8	("3534234" "3586542" "3622382" "3648125" "3649386").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2005/12/07 14:19
S20	0	"08313350"	US-PGPUB; USPAT; USOCR	ADJ	ON	2005/12/07 14:20
S21	0	"6979877".pn.	US-PGPUB; USPAT; USOCR	ADJ	ON	2005/12/07 14:20
S22	0	("6979877").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/07 14:20

S23	1	S14 and barrier	US-PGPUB; USPAT	ADJ	ON	2005/12/07 15:24
S24	1	S14 and terminal	US-PGPUB; USPAT	ADJ	ON	2005/12/07 15:27
S25	1	S14 and micron	US-PGPUB; USPAT	ADJ	ON	2005/12/07 15:27
S26	1	us-20040144999-\$.did.	US-PGPUB; USPAT	ADJ	ON	2005/12/08 07:38
S27	1	S26 and terminal	US-PGPUB; USPAT	ADJ	ON	2005/12/08 07:57
S28	12929974	@ad<"19950607" or @rlad<"19950607"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:59
S29	27203	(thickness or depth) with accuracy	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 08:00
S30	13017	S28 and S29	US-PGPUB; USPAT;	ADJ	ON	2005/12/08 08:00
			EPO; JPO; DERWENT; IBM_TDB			
S31	121	S29 same (void or microcrack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:42
S32	399	S29 and (void or microcrack) and S28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:07
S33	69	S31 and S28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 08:03
S34	72	S32 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 08:05
S35	779337	"MU" OR MICROMETER OR MICRON	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 08:06

S36	112114	angstrom or ".angstrom."	US-PGPUB; USPAT;	OR	ON	2005/12/08 08:07
			EPO; JPO; DERWENT; IBM_TDB			
S37	842404	S35 or S36	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 08:08
S38	39	(S29 same S37) and (void or microcrack) and S28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 08:09
S39	145	(S29 same S37) and S28 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 09:36
S40	97228	"ang"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 08:24
S41	58	(S29 same S40) and S28 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 09:51
S42	729641	"+-"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 09:52
S43	4	S41 and (void or microcrack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:09
S44	3	S41 and (crack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:41
S45	514	MO-CVD	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:41

S46	2	S45 same (void or microcrack or crack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:43
S47	48	S45 and (void or microcrack or crack)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:47
S48	35	"154,300"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:51
S49	9	S48 and implantation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:58
S50	3	"154,300".ap.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:51
S51	6902	(oxygen or nitrogen) with implantation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 10:59
S52	2240	S28 and S51	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 11:00
S53	28	pn same S51 and S28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 11:18
S54	1931	(silicon oxide) with diameter	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2005/12/08 11:19
S55	193251	"ang" angstrom	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 11:19

S56	106	S54 with S55	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 12:33
S57	1	S26 and atomic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 12:36
S58	3	"3341754".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/08 13:53
S59	1482	(257/506,509,515).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/08 13:54